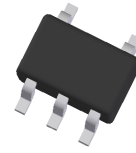


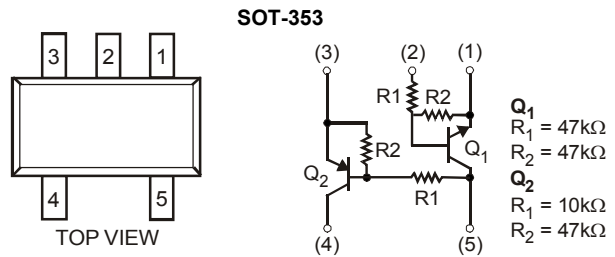
### Features

- Epitaxial Planar Die Construction
- Surface Mount Package Suited for Automated Assembly
- Simplifies Circuit Design and Reduces Board Space
- Lead Free/RoHS Compliant (Note 1)
- "Green" Device (Note 2)



### Mechanical Data

- Case: SOT-353
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminal Connections: See Diagram
- Terminals: Finish – Matte Tin Annealed Over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208
- Marking Information: See Page 4
- Ordering Information: See Page 4
- Weight: 0.006 grams (approximate)



### Maximum Ratings, Total Device @ $T_A = 25^\circ C$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 3)	$P_D$	150	mW
Thermal Resistance, Junction to Ambient Air (Note 3)	$R_{\theta JA}$	833	$^\circ C/W$
Operating and Storage Temperature Range	$T_j, T_{STG}$	-55 to +150	$^\circ C$

### Maximum Ratings, Pre-Biased NPN Transistor, $Q_1$ @ $T_A = 25^\circ C$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Supply Voltage	$V_{CC}$	50	V
Input Voltage	$V_{IN}$	-10 to +40	V
Output Current	$I_O$	30	mA
Collector Current	$I_{C(MAX)}$	100	mA

### Maximum Ratings, Pre-Biased PNP Transistor, $Q_2$ @ $T_A = 25^\circ C$ unless otherwise specified

Characteristic	Symbol	Value	Unit
Supply Voltage	$V_{CC}$	-50	V
Input Voltage	$V_{IN}$	-40 to +6	V
Output Current	$I_O$	-100	mA
Collector Current	$I_{C(MAX)}$	-100	mA

- Notes:
1. No purposefully added lead.
  2. Diodes Inc.'s "Green" policy can be found on our website at [http://www.diodes.com/products/lead\\_free/index.php](http://www.diodes.com/products/lead_free/index.php).
  3. Device mounted on FR-4 PCB; pad layout as shown on Diodes Inc. suggested pad layout document AP02001, which can be found on our website at <http://www.diodes.com/datasheets/ap02001.pdf>.

## Electrical Characteristics, Pre-Biased NPN Transistor, Q<sub>1</sub> @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	V <sub>I(off)</sub>	—	—	0.5	V	V <sub>CC</sub> = 5V, I <sub>O</sub> = 100μA
	V <sub>I(on)</sub>	3	—	—	V	V <sub>O</sub> = 0.3V, I <sub>O</sub> = 2mA
Output Voltage	V <sub>O(on)</sub>	—	0.1	0.3	V	I <sub>O</sub> /I <sub>I</sub> = 10mA/0.5 mA
Input Current	I <sub>I</sub>	—	—	0.18	mA	V <sub>I</sub> = 5V
Output Current	I <sub>O(off)</sub>	—	—	0.5	μA	V <sub>CC</sub> = 50V, V <sub>I</sub> = 0V
DC Current Gain	G <sub>I</sub>	68	—	—	—	V <sub>O</sub> = 5V, I <sub>O</sub> = 5mA
Gain-Bandwidth Product	f <sub>T</sub>	—	250	—	MHz	V <sub>CE</sub> = 10V, I <sub>E</sub> = -5mA, f = 100MHz*
Input Resistance	R <sub>1</sub>	32.9	47	61.1	kΩ	—
Resistance Ratio	R <sub>2</sub> /R <sub>1</sub>	0.8	1	1.2	—	—

\*Characteristic of Transistor – for reference only.

## Electrical Characteristics, Pre-Biased PNP Transistor, Q<sub>2</sub> @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Input Voltage	V <sub>I(off)</sub>	—	—	-0.3	V	V <sub>CC</sub> = -5V, I <sub>O</sub> = -100μA
	V <sub>I(on)</sub>	-1.4	—	—	V	V <sub>O</sub> = -0.3V, I <sub>O</sub> = -1mA
Output Voltage	V <sub>O(on)</sub>	—	-0.1	-0.3	V	I <sub>O</sub> /I <sub>I</sub> = -5mA/-0.25 mA
Input Current	I <sub>I</sub>	—	—	-0.88	mA	V <sub>I</sub> = -5V
Output Current	I <sub>O(off)</sub>	—	—	-0.5	μA	V <sub>CC</sub> = -50V, V <sub>I</sub> = 0V
DC Current Gain	G <sub>I</sub>	68	—	—	—	V <sub>O</sub> = -5V, I <sub>O</sub> = -5mA
Gain-Bandwidth Product	f <sub>T</sub>	—	250	—	MHz	V <sub>CE</sub> = -10V, I <sub>E</sub> = 5mA, f = 100MHz*
Input Resistance	R <sub>1</sub>	7	10	13	kΩ	—
Resistance Ratio	R <sub>2</sub> /R <sub>1</sub>	3.7	4.7	5.7	—	—

\*Characteristic of Transistor – for reference only.

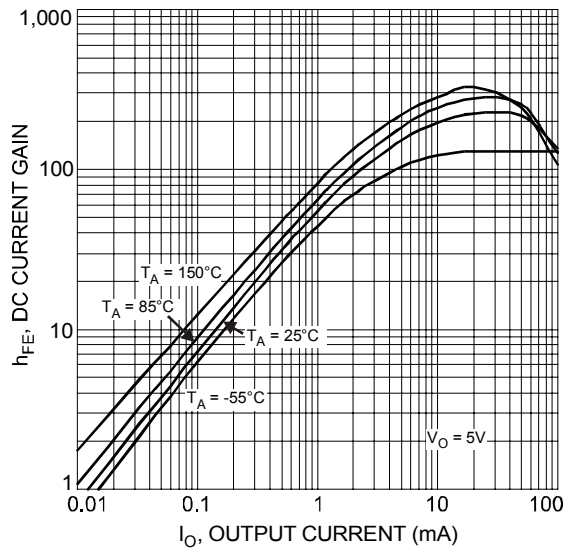


Fig. 1 Typical DC Current Gain vs. Output Current (Q<sub>1</sub>, NPN)

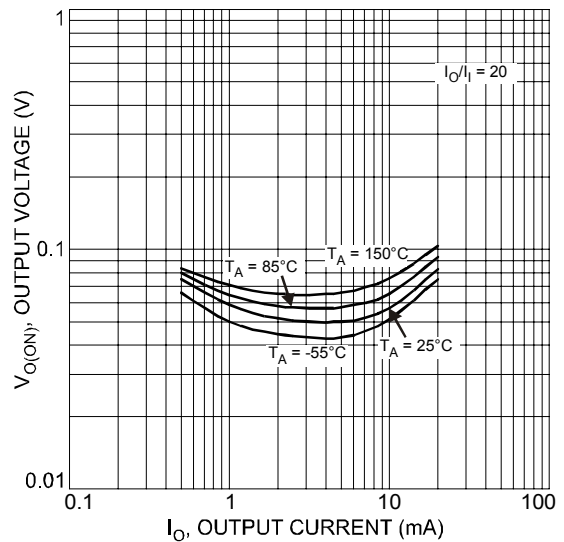


Fig. 2 Typical Output Voltage vs. Output Current (Q<sub>1</sub>, NPN)

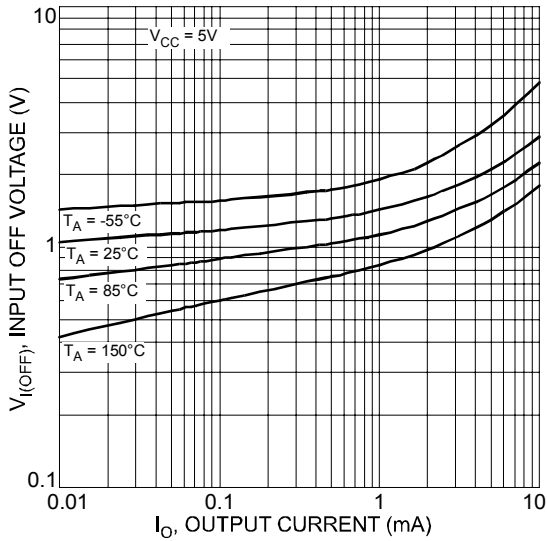


Fig. 3 Typical Input OFF Voltage vs. Output Current (Q1, NPN)

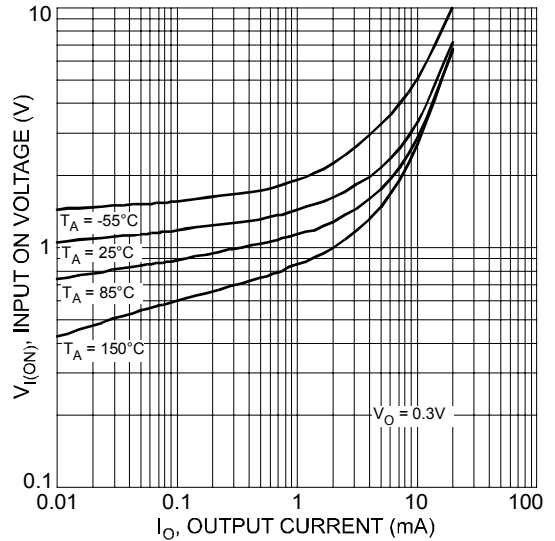


Fig. 4 Typical Input ON Voltage vs. Output Current (Q1, NPN)

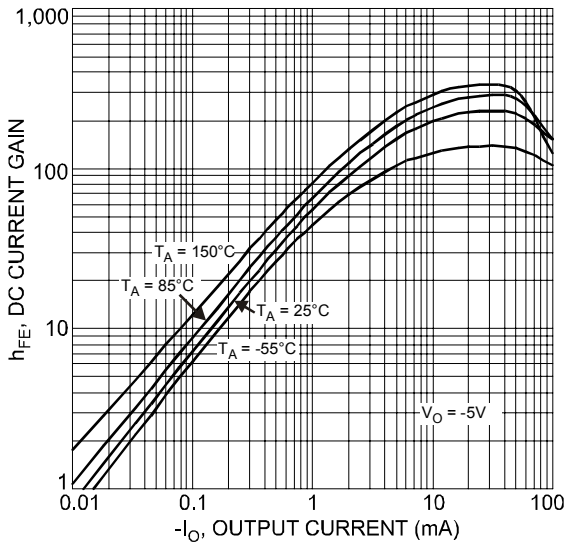


Fig. 5 Typical DC Current Gain vs. Output Current (Q2, PNP)

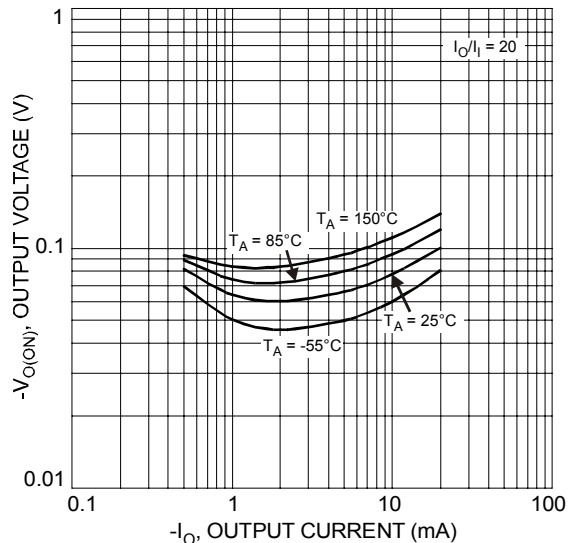


Fig. 6 Typical Output Voltage vs. Output Current (Q2, PNP)

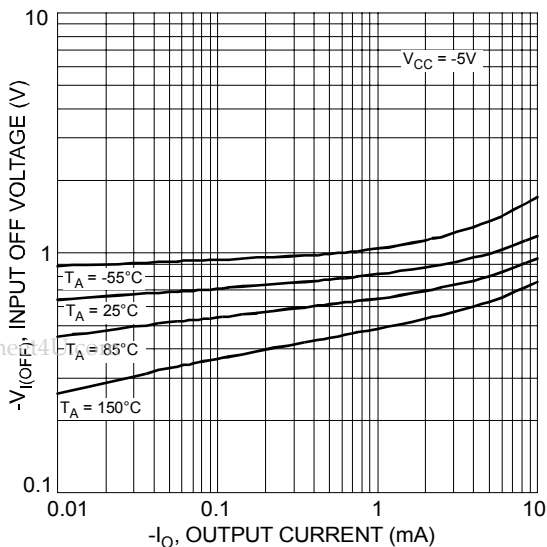


Fig. 7 Typical Input OFF Voltage vs. Output Current (Q2, PNP)

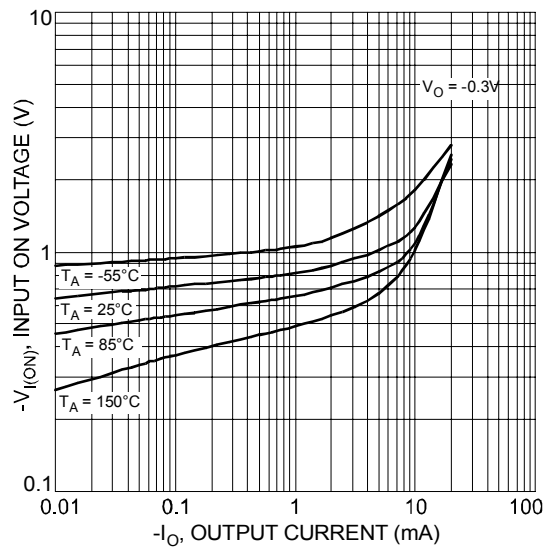


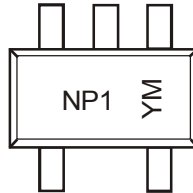
Fig. 8 Typical Input ON Voltage vs. Output Current (Q2, PNP)

## Ordering Information (Note 4)

Device	Packaging	Shipping
UMC4N-7	SOT-353	3000/Tape & Reel

Notes: 4. For packaging details, go to our website at <http://www.diodes.com/datasheets/ap02007.pdf>.

## Marking Information



NP1 = Product Type Marking Code  
 YM = Date Code Marking  
 Y = Year ex: U = 2007  
 M = Month ex: 9 = September

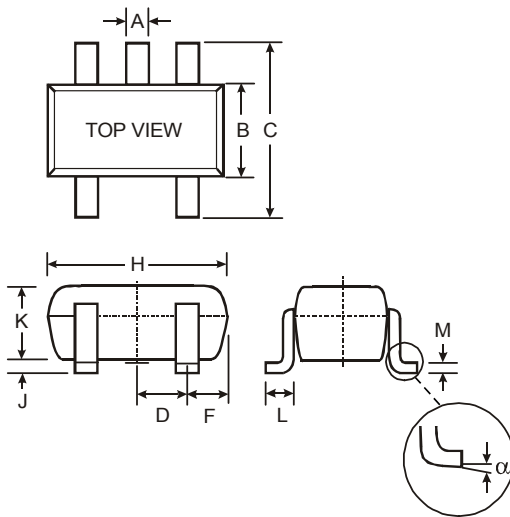
### Date Code Key

Year Code	2007	2008	2009	2010	2011	2012
Year Code	U	V	W	X	Y	Z

Month Code	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Month Code	1	2	3	4	5	6	7	8	9	O	N	D

## Package Outline Dimensions



SOT-353		
Dim	Min	Max
A	0.10	0.30
B	1.15	1.35
C	2.00	2.20
D	0.65 Nominal	
F	0.30	0.40
H	1.80	2.20
J	—	0.10
K	0.90	1.00
L	0.25	0.40
M	0.10	0.25
α	0°	8°
All Dimensions in mm		

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